

### 5 A Schottky Barrier Rectifier

#### DESCRIPTION

This UPS540e3 in the Powermite3<sup>®</sup> package is a high efficiency Schottky rectifier that is also RoHS compliant offering high current/power capabilities previously found only in much larger packages. They are ideal for SMD applications that operate at high frequencies. In addition to its size advantages, the Powermite3<sup>®</sup> package includes a full metallic bottom that eliminates the possibility of solder flux entrapment during assembly and a unique locking tab act as an efficient heat path to the heat-sink mounting. Its innovative design makes this device ideal for use with automatic insertion equipment.

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

ABSOLUTE MAXIMUM RATINGS AT 25° C (UNLESS OTHERWISE SPECIFIED)				
Rating	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	40	V	
RMS Reverse Voltage	V <sub>R (RMS)</sub>	28	V	
Average Rectified Output Current	Ιo	5	A	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine wave Superimposed on Rated Load@ T <sub>c</sub> =90 °C	I <sub>FSM</sub>	100	А	
Storage Temperature	T <sub>STG</sub>	-55 to +150	°C	

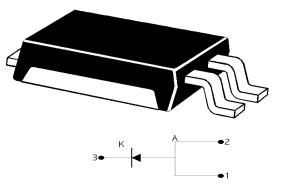
#### THERMAL CHARACTERISTICS

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Thermal Resistance	_		
Junction-to-case (bottom)	R <sub>eJC</sub>	3.2	°C/ Watt
Junction to ambient (1)	R <sub>0JA</sub>	65	°C/ Watt
(1) When mounted on FR-4 PC board using 2 oz copper with recommended minimum foot print			

#### Powermite 3<sup>™</sup>

Junction Temperature



#### **KEY FEATURES**

- Very low thermal resistance package
- RoHS Compliant with e3 suffix part number
- Guard-ring-die construction for transient protection
- Efficient heat path with Integral locking bottom metal tab
- Low forward voltage
- Full metallic bottom eliminates flux
  entrapment
- Compatible with automatic insertion
- Low profile-maximum height of 1mm

#### **APPLICATIONS/BENEFITS**

- Switching and Regulating Power Supplies.
- Silicon Schottky (hot carrier) rectifier for minimal reverse voltage recovery
- Elimination of reverse-recovery oscillations to reduce need for EMI filtering
- Charge Pump Circuits
- Reduces reverse recovery loss with low I<sub>RM</sub>
- Small foot print 190 X 270 mils (1:1 Actual size) See mounting pad details on pg 3

#### MECHANICAL & PACKAGING

- CASE: Void-free transfer molded thermosetting epoxy compound meeting UL94V-0
- FINISH: Annealed matte-Tin plating over copper and readily solderable per MIL-STD-750 method 2026 (consult factory for Tin-Lead plating)
- POLARITY: See figure (left)
- MARKING: S540
- WEIGHT: 0.072 gram (approx.)
- Package dimension on last page
- Tape & Reel option: 16 mm tape per Standard EIA-481-B, 5000 on 13" reel

-55 to +125

°С

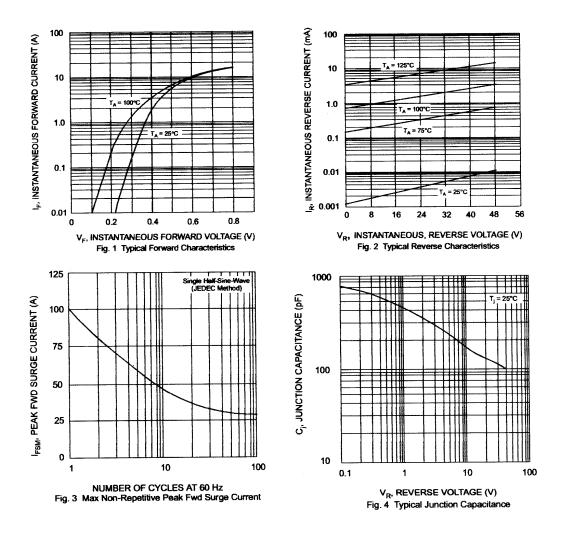
UPS340e3



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Parameter	Symbol	Conditions	Min	Тур.	Max	Units
Forward Voltage (Note 1)	V <sub>F</sub>	$ \begin{split} I_F &= 5 \; A \;, \; T_j = 25 \; ^{o}C \\ I_F &= 5 \; A \;, \; T_j = 125 \; ^{o}C \\ I_F &= 10 \; A \;, \; T_j = 25 \; ^{o}C \\ I_F &= 10 \; A \;, \; T_j = 125 \; ^{o}C \end{split} $		0.47 0.45 0.62 0.59	0.54	V
Reverse Break Down Voltage Note 1)	V <sub>BR</sub>	I <sub>R</sub> = 0.5 mA	40			V
Reverse Current (Note1)	IF	V <sub>R</sub> = 40 V, T <sub>j</sub> = 25°C V <sub>R</sub> = 40 V, T <sub>j</sub> =125 °C		0.030 2.5	0.5 20	mA
Capacitance	CT	V <sub>R</sub> = 4 V; F = 1 MH <sub>Z</sub>		250		pF

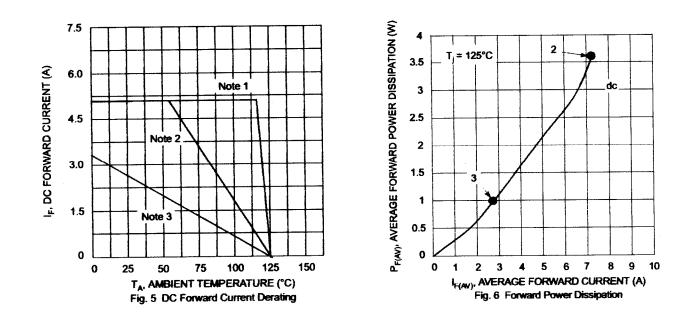
Note: 1 Short duration test pulse used to minimize self - heating effect



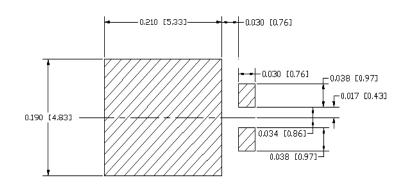
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- Notes: 1. T<sub>A</sub> = T<sub>SOLDERING POINT</sub>, R<sub>ΘJS</sub>=3.2°C/W, R<sub>Θsa</sub> = 0° C/W.
  2. Device mounted on GETEK substrate, 2" x 2", 2 oz. copper, double-sided, cathode pad dimensions 0.75" x 1.0", anode pad dimensions 0.25" x 1.0". R<sub>ΘJA</sub> in range of 15-30° C/W.
  - 3. Device mounted on FRA-4 substrate, 2" x 2", 2 oz. copper, single-sided, pad layout  $R_{\Theta JA}$  in range of 65° C/W. See mounting pad below.

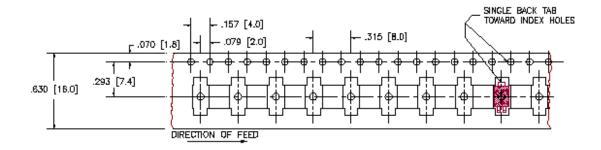


Mounting Pad Dimensions: inches [mm]

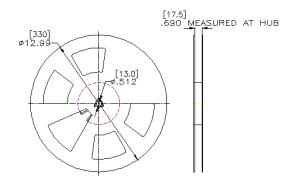


## 5 A Schottky Barrier Rectifier

16 mm TAPE



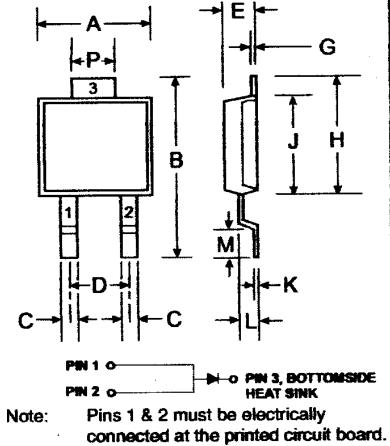
## 13 INCH REEL





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#### DIMENSIONS

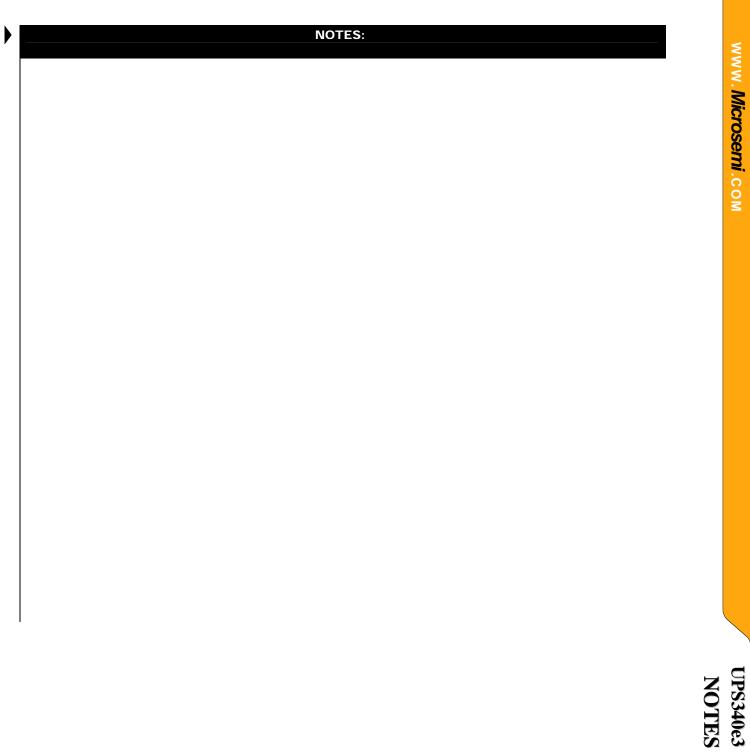


POWERMITE®3		
Dim	Min	Max
A	4.03	4.09
В	6.40	6.61
C	.889 NOM	
D	1.83 NOM	
E	1.10	1.14
G	.178 NOM	
н	5.01	5.17
J	4.37	4.43
К	.178 NOM	
L	.71	.77
M	.36	.46
Р	1.73	1.83
All Dimensions in mm		

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